



Tranzystor 2N1725;TO-61;NPN;5A;80V; 50W;10MHz



Dane techniczne:

Nazwa: 2N1725

Typ tranzystora: bipolarny

Kierunek przewodnictwa: NPN

Prąd kolektora: 5A

Napięcie kolektor-emiter: 80V

Moc: 50W

Częstotliwość: 10MHz

Obudowa: TO-61

2N1722
2N1722A
2N1723
2N1724
2N1724A
2N1725

Triple Diffused Power Transistors

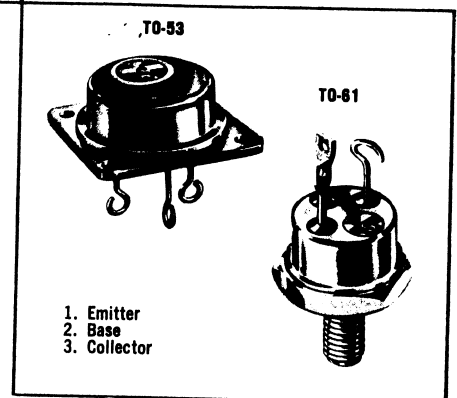
These NPN silicon triple diffused power transistors can be used to advantage in power amplifiers and switching applications where high voltage and low saturation resistance are required. These transistors are designed to meet all of the electrical and mechanical requirements of Mil S19500B. The 2N1722 and 2N1724 types are available to either JAN or JAN TX specifications from stock.

FEATURES

- 15 MHz typical Gain-Bandwidth — ft
- High Sustaining Voltage
- Very Low Leakage Currents
- 50 Watts Dissipation at 100°C
- TO-61, TO-53 Packages

APPLICATIONS

- High power, High frequency inverters
- Converters
- High Power Linear Amplifiers
- High Speedswitching Type Regulated Power Supplier
- RF Power Amplification Up to 10 MHz

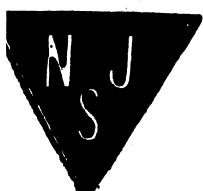


ABSOLUTE MAXIMUM RATINGS AT 25°C CASE TEMPERATURE (unless otherwise noted)

	JAN2N1724 JAN2N1722	2N1724 2N1722	2N1724A 2N1722A	2N1725 2N1723	UNITS
Collector — Base Voltage	175	120	180	120	Volts
Collector — Emitter Voltage	80	80	120	80	Volts
Emitter — Base Voltage	10	10	10	10	Volts
Collector Current, Continuous	5	5	5	5	Amps
Collector Current, Peak		7.5	7.5	5	Amps
Emitter Current, Continuous			6	5	Amps
Base Current, Continuous			1		Amps
Safe Continuous Operating Region	SEE FIGURE				
Collector Power Dissipation 25°C Free Air Temperature	3	3	3	3	Watts
Collector Power Dissipation 100°C Case Temperature	50	50	50	50	Watts
Operating Collector Junction Temperature	175	175	175	175	°C
Storage Temperature Range	-65 TO 200				°C


ELECTRICAL CHARACTERISTICS AT 25°C CASE TEMP (unless otherwise noted)

CHARACTERISTIC	TEST CONDITION	JAN2N1724 JAN2N1722		2N1724 2N1722		2N1724A 2N1722A		2N1725 2N1723		UNITS
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
BV_{CEO} (sust)	$I_C = 200mA, I_E = 0$	80		80		120		80		Volts
BV_{EBO}	$I_C = 0, I_E = 10mA$	10			10				0.5	Volts
I_{EBO}	$V_{EB} = 3V, I_C = 0$		400							mA
I_{CES}	$V_{EB} = 7V, I_C = 0$				10					mA
	$V_{EB} = 9V, I_C = 0$						0.5		0.5	mA
	$V_{EB} = 10V, I_C = 0$						10		10	mA
	$V_{CE} = 30V, V_{EB} = 0$						10		10	mA
	$V_{CE} = 60V, V_{EB} = 0$		0.3		1		0.1		0.1	mA
	$V_{CE} = 100V, V_{EB} = 0$		1.5		2		1.0		1	mA
I_{CBO}	$V_{CE} = 100V, V_{EB} = 0, T_C = 150°C$					2.0			2	mA
	$V_{CE} = 120V, V_{EB} = 0, T_C = 150°C$				10				10	mA
	$V_{CE} = 180V, V_{EB} = 0, T_C = 150°C$		10							mA
	$V_{CE} = 175V, I_E = 0$		5				10			mA
h_{FE}	$V_{CE} = 3V, I_E = 0$				0.5		0.1		0.1	mA
	$V_{CE} = 15V, I_C = 0.1A$	30		20		30		50		mA
	$V_{CE} = 15V, I_C = 2A$	30	90	20	90	30	90	50	150	mA
V_{BE}	$V_{CE} = 5V, I_C = 5A$					20				Volts
	$V_{CE} = 15V, I_C = 2A, T_C = -55°C$	18		12		18		25		Volts
	$I_C = 2A, I_E = 0.2A$		1.2		2.0		1.2		2.0	Volts
V_{CE} (sat)	$I_C = 5A, I_E = 0.5A$		0.6		1.0		0.6		1.0	Volts
	$I_C = 2A, I_E = 0.2A$						1.5			Volts
	$I_C = 5A, I_E = 0.5A$						0.8			Volts
	$I_C = 2A, I_E = 0.2A, T_C = -55°C$						1.0			Volts
V_{CE} (floating potential)	$V_{CE} = 180V, I_E = 0$									Volts
h_{FE}	$V_{CE} = 15V, I_C = 0.5A, f = 10MHz$	1.0		1.0		1.0		1.0		
C_{cb}	$V_{CE} = 15V, I_C = 0, f = 1MHz$		550		550		550		550	pf



NEW ENGLAND SEMICONDUCTOR

BIPOLAR NPN TRANSISTOR TO-61

PACKAGE	DEVICE TYPE	V _{CEO} (sus) VOLTS	I _C (max) AMPS	h _{FE} @ I _C /V _{CE} (min/max @ A/V)	V _{CE(sat)} @ I _C /I _B (V @ A/A)	P _D * WATTS	f _T (MHz)
	2N1724 [^]	80	5	20-90@15	1@2/2	50	10
	2N1724A	120	5	30-90@2/15	.6@2/2	50	10
	2N1725	80	5	50-150@2/15	1@2/2	50	10
	2N2811	50	10	20-60@5/5	.5@5/5	40	15
	2N2812	50	10	40-120@5/5	.5@5/5	40	15
	2N2813	70	10	20-60@5/5	.5@5/5	40	15
	2N2814	70	10	40-120@5/5	.5@5/5	40	15
	2N3489	100	7.5	15-45@3/5	1.2@3/3	67	10
	2N3490	60	7.5	40-120@5/5	1.5@5/5	67	10
	2N3491	80	7.5	40-120@5/5	1.5@5/5	67	10
	2N3492	100	7.5	30-90@5/5	1.5@5/5	67	10
	2N3597	40	20	40-120@10/2	1.5@20/2	100	30
	2N3598	60	20	40-120@10/2	1.5@20/2	100	30
	2N3599	80	20	40-120@10/2	1.5@20/2	100	30
	2N4301	80	10	30-120@5/4	.4@5/5	50	40
	2N5389	300	7.5	25-100@2/5	2.2@7/1.4	100	15
	2N5540	300	10	20-60@5/5	1@8/8	50	20

* T_C = 25°C

^h V_{CER}

[^] Available in JAN, JANTX, JANTXV